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Application No.		Filing Date		Examiner	Art Unit
09/735,903-Conf. #5750		December 14, 2000		F. Erdem	2826
Applicant(s): Ichir	o Fujiwara et a	al.			
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				OR PATENTS	
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	Claims Remaining After	Highest Number Previously	Number Extra Claims		
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MATOR	11-			Dated: F	February 18, 2005
Ronald R Maria Attorney Regi. N	nen				
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RADER, FISHW 1233 20th Stree		R PLLC			
Suite 501	•			•	
Washington, DC (202) 955-3750	20036				
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Docket No.: SON-1966

(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:

Ichiro Fujiwara et al.

Application No.: 09/735,903 Confirmation No.: 5750

Filed: December 14, 2000 Art Unit: 2826

For: NONVOLATILE SEMICONDUCTOR

MEMORY DEVICE AND METHOD FOR

OPERATING THE SAME

Examiner: F. Erdem

AMENDMENT IN RESPONSE TO NON-FINAL OFFICE ACTION

MS Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

INTRODUCTORY COMMENTS

In response to the Office Action dated February 7, 2005, please amend the above-identified U.S. patent application as follows:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 12 of this paper.